













CSD17551Q3A

SLPS386B - SEPTEMBER 2012-REVISED JANUARY 2016

CSD17551Q3A 30-V N-Channel NexFET™ Power MOSFETs

Features

- Ultra-Low Qa and Qad
- Low Thermal Resistance
- Avalanche Rated
- Pb Free
- **RoHS Compliant**
- Halogen Free
- SON 3.3 mm × 3.3 mm Plastic Package

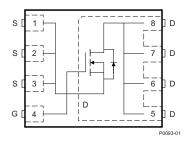
2 Applications

- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Optimized for Control FET Applications

Description

This 30 V, 7.8 m Ω , 3.3 mm × 3.3 mm NexFETTM power MOSFET is designed to minimize losses in power conversion applications.





Product Summary

T _A = 25°	С	TYPICAL VA	UNIT			
V_{DS}	Drain-to-Source Voltage 30					
Q_g	Gate Charge Total (4.5 V) 6.0					
Q_{gd}	Gate Charge Gate-to-Drain	1.5	nC			
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 4.5 V	9.6	mΩ		
	Drain-to-Source On Resistance	V _{GS} = 10 V	7.8	mΩ		
V _{GS(th)}	Threshold Voltage 1.6					

Ordering Information⁽¹⁾

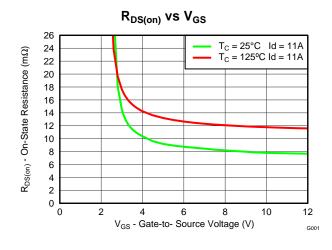
DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD17551Q3A	2500	13-Inch Reel	SON	Tape and
CSD17551Q3AT	250	7-Inch Reel	3.3 mm x 3.3 mm Plastic Package	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	30	V
V_{GS}	Gate-to-Source Voltage	±20	٧
	Continuous Drain Current, T _C = 25°C	48	Α
I_D	Continuous Drain Current, Silicon Limited	48	Α
	Continuous Drain Current, T _A = 25°C ⁽¹⁾	12	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	71	Α
P_D	Power Dissipation ⁽¹⁾	2.6	W
T _J , T _{stg}	Operating Junction Temperature, Storage Temperature	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 25 \text{ A}, L = 0.1 \text{ mH}, R_G = 25 \Omega$	31	mJ

- (1) Typical $R_{\theta JA}=48^{\circ} C/W$ on a 1 inch 2 (6.45 cm 2), 2 oz. (0.071 mm thick) Cu pad on a 0.06 inch (1.52 mm) thick FR4 PCB.
- (2) Pulse duration ≤300 µs, duty cycle ≤2%



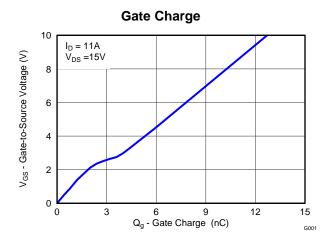




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (June 2014) to Revision B	Page
Enhanced Description text.	1
Added Community Resources section	
Updated package drawing	8
Updated PCB drawing	g
Updated Stencil Pattern drawing.	
Changes from Original (September 2012) to Revision A	Page
Changed "Pb-Free terminal plating" feature to state "Pb Free"	1

Updated package dimensions.



5 Specifications

5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	30			V
I _{DSS}	Drain-to-source leakage current	$V_{GS} = 0 \text{ V}, V_{DS} = 24 \text{ V}$			1	μΑ
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.1	1.6	2.1	V
_	Dunin to course on resistance	V _{GS} = 4.5 V, I _D = 11 A		9.6	11.8	mΩ
R _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 10 V, I _D = 11 A		7.8	9	mΩ
9 _{fs}	Transconductance	V _{DS} = 15 V, I _D = 11 A		101		S
DYNAM	IC CHARACTERISTICS		,			
C _{iss}	Input capacitance			1050	1370	рF
C _{oss}	Output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 15 \text{ V}, f = 1 \text{ MHz}$		244	317	pF
C _{rss}	Reverse transfer capacitance			24	31	pF
R _G	Series gate resistance			1.5	3	Ω
Qg	Gate charge total (4.5 V)			6	7.8	nC
Q _{gd}	Gate charge gate to drain			1.5		nC
Q _{gs}	Gate charge gate to source	V _{DS} = 15 V, I _D = 11 A		2.3		nC
Q _{g(th)}	Gate charge at V _{th}			1.4		nC
Q _{oss}	Output charge	V _{DS} = 15 V, V _{GS} = 0 V		7.4		nC
t _{d(on)}	Turn on delay time			8		ns
t _r	Rise time	V _{DS} = 15 V, V _{GS} = 4.5 V,		24		ns
t _{d(off)}	Turn off delay time	$I_{DS} = 11 \text{ A}, R_G = 2 \Omega$		12		ns
t _f	Fall time			3.4		ns
DIODE (CHARACTERISTICS	•	1			
V _{SD}	Diode forward voltage	I _{SD} = 11 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse recovery charge	V _{DS} = 13.5 V, I _F = 11 A,		13		nC
t _{rr}	Reverse recovery time	di/dt = 300 A/µs		14		ns

5.2 Thermal Information

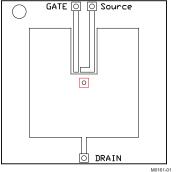
(T_A = 25°C unless otherwise stated)

	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance ⁽¹⁾			3.9	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance (1)(2)			60	°C/W

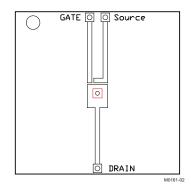
⁽¹⁾ R_{θ,JC} is determined with the device mounted on a 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 1.5 inches x 1.5 inches (3.81 cm x 3.81 cm), 0.06 inch (1.52 mm) thick FR4 PCB. R_{θ,JC} is specified by design, whereas R_{θ,JA} is determined by the user's board design.

(2) Device mounted on FR4 material with 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu.





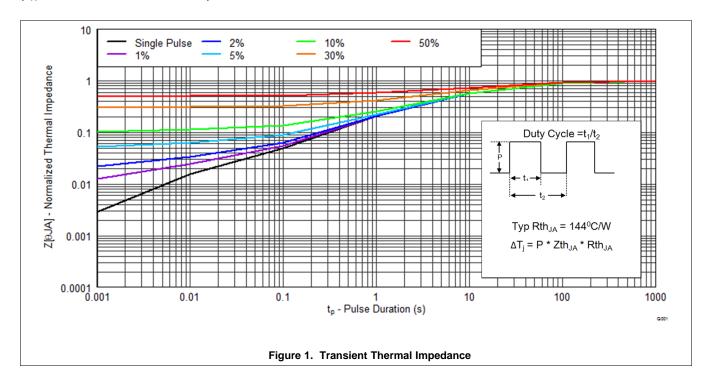
Max $R_{\theta JA} = 60^{\circ} \text{C/W}$ when mounted on 1 inch² (6.45 cm²) of 2 oz. (0.071 mm thick) Cu.



Max $R_{\theta JA} = 144^{\circ} C/W$ when mounted on a minimum pad area of 2 oz. (0.071 mm thick) Cu.

5.3 Typical MOSFET Characteristics

(T_A = 25°C unless otherwise stated)

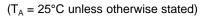


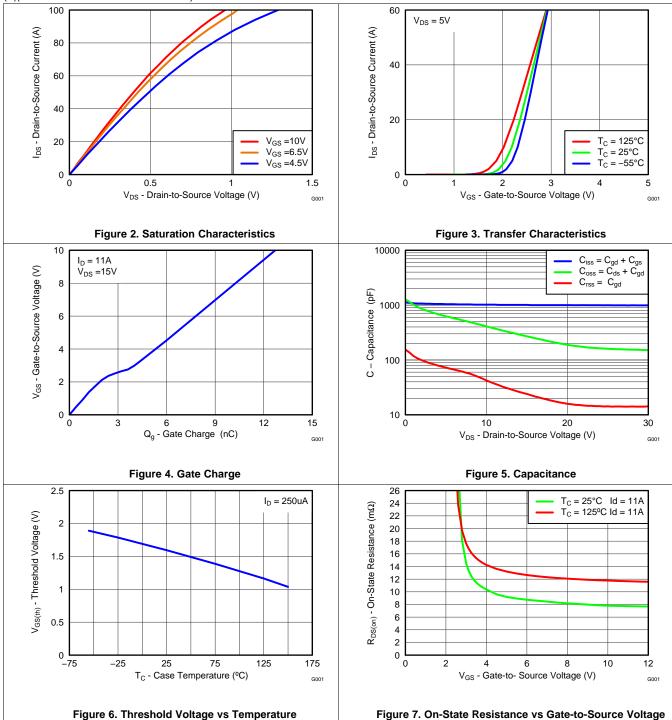
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Typical MOSFET Characteristics (continued)

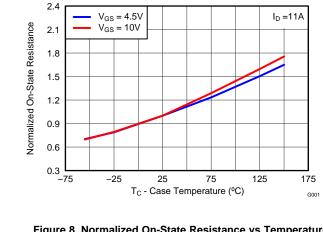






Typical MOSFET Characteristics (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



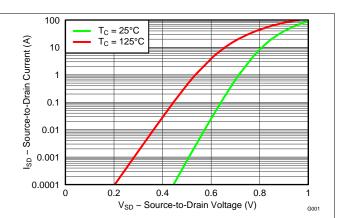
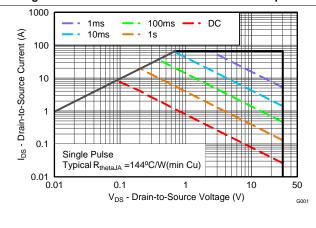


Figure 8. Normalized On-State Resistance vs Temperature

Figure 9. Typical Diode Forward Voltage



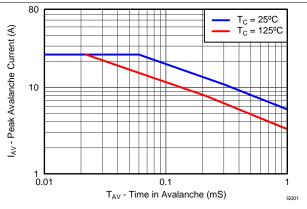


Figure 10. Maximum Safe Operating Area

Figure 11. Single Pulse Unclamped Inductive Switching

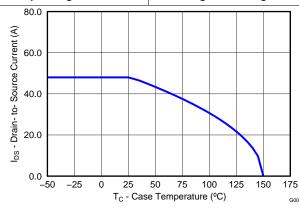


Figure 12. Maximum Drain Current vs Temperature

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6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Lise

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

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6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

SLYZ022 — TI Glossary.

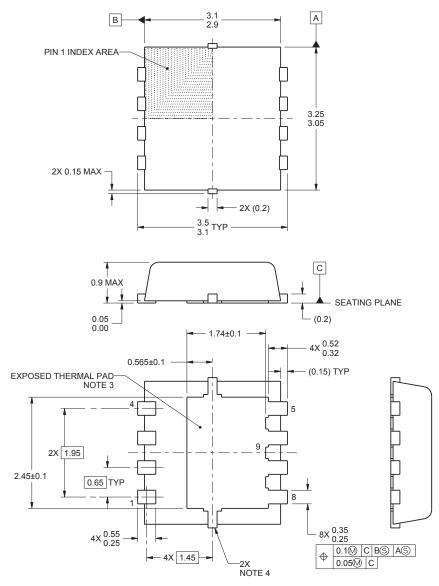
This glossary lists and explains terms, acronyms, and definitions.



7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q3A Package Dimensions



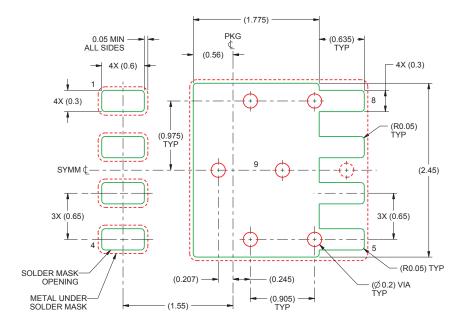
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
- 4. Metalized features are supplier options and may not be on the package.
- 5. All dimensions do not include mold flash or protrusions.

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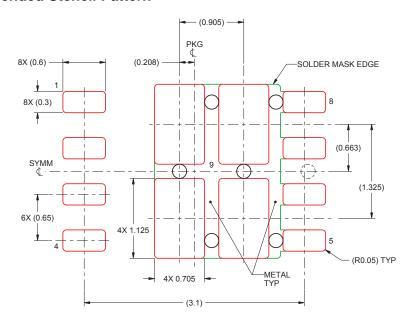
7.2 Q3A Recommended PCB Pattern



- 1. This package is designed to be soldered to a thermal pad on the board. For more information, see the *QFN/SON PCB Attachment* application report, SLUA271.
- Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

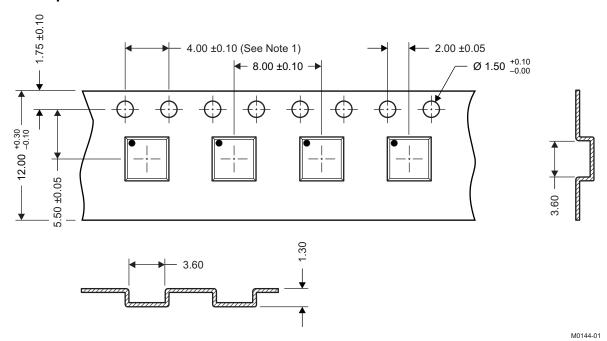
7.3 Q3A Recommended Stencil Pattern



1. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



7.4 Q3A Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: 0.30 ±0.05 mm
- 6. MSL1 260°C (IR and convection) PbF-reflow compatible

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PACKAGE OPTION ADDENDUM

11-Jan-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD17551Q3A	ACTIVE	VSONP	DNH	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	17551	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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